NSN 5961-00-506-3080

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View Online at https://aerobasegroup.com/nsn/5961-00-506-3080 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** 0.300 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage, dc and 100.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** 7.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 07148-80918 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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